

**ifw** optronics

SiC-Photodiode JEA0,25L JEAC0,25L

preliminary data sheet

characteristics :

- ◆ low cost SiC-Photodiode with lense cap
- ◆ active area: 0,25 mm²
- ◆ spectral range: 205 ... 355 nm
- ◆ high UV-responsivity: 0,18 A/W
- ◆ hermetically sealed TO-package
- ◆ option for isolated assembly of photodiode
- ◆ HT-option for extended working temperature range 150°C
- ◆ RoHS, REACH and WEEE conform

applications :

- ◆ optical measurements in UV-range
- ◆ control of sterilization lamps
- ◆ flame control

absolute maximum ratings :

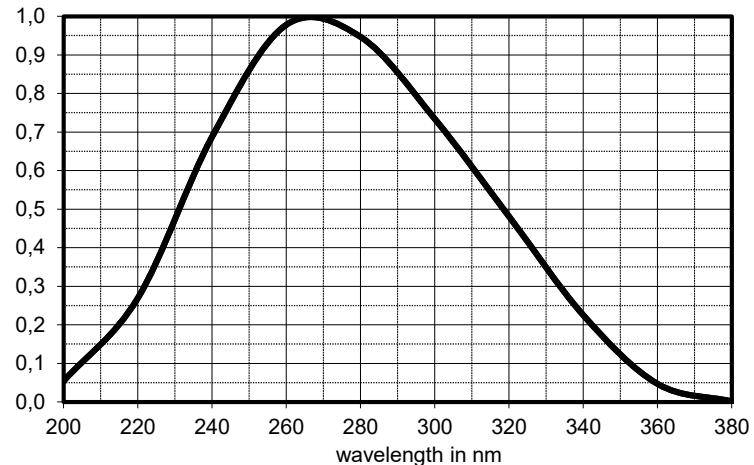
- ◆ reverse voltage 10 V
- ◆ operating temperature range - 40 °C ... 125 °C
- ◆ storage temperature range - 40 °C ... 125 °C
- ◆ soldering temperature (3s) 260 °C

technical data :

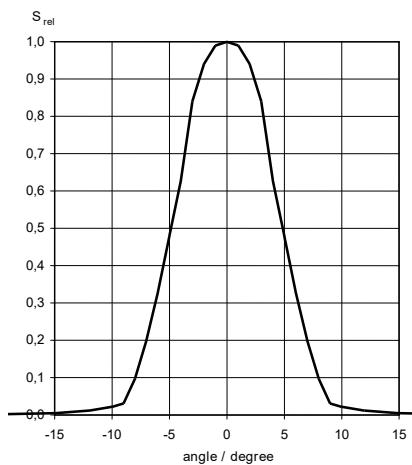
test conditions, as not otherwise specified: T_A = 25 °C , V_R = 0 V

parameter	Test - conditions	JEA0,25L	JEAC0,25L	unit
active area		0,55 x 0,55		mm ²
spectral range				
λ _{min}	S = 0,1 x S _{max}	205		nm
λ _{max}		355		nm
maximum of spectral responsivity		265		nm
maximum sensitivity S _{max}	λ = 265 nm	0,18		A/W
absolute sensitivity S _{254nm}	λ = 254 nm	0,16		A/W
dark current I _R	V _R = 1 V	25		fA
junction capacitance C	f = 10 kHz	75		pF

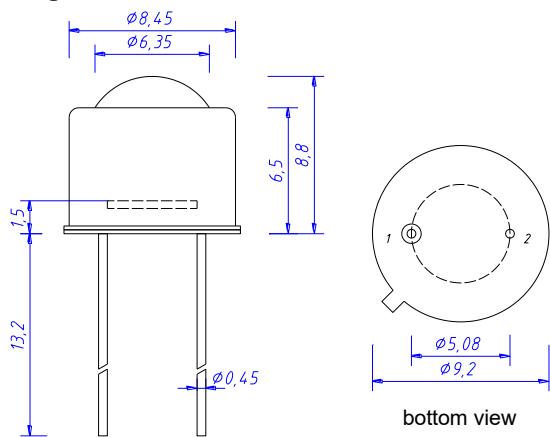
relative spectral sensitivity



relative angular response



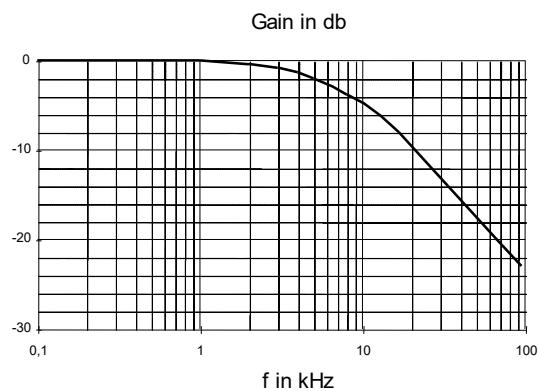
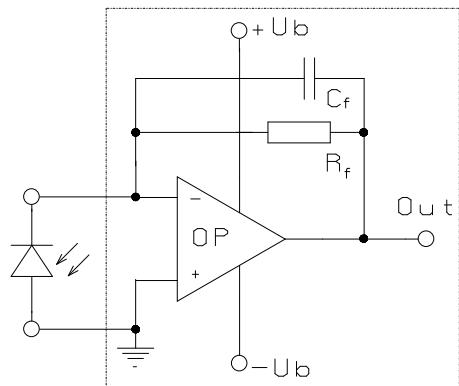
package dimensions



JEA 0,25L: 1 Anode
2 Cathode+Case

JEAC 0,25L: 1 = Cathode
2 = Anode + Case

application example



The application example shows a typical circuit. R_f is responsible for the gain of the circuit. C_f compensates the reverse junction capacitance of the photodiode and the input capacitance of the OP-amp. The exact value of C_f depends on R_f , used OP-amp and capacitance of the circuit. A typical value is 1pF.

The chart shows dependence of amplitude of the application circuit with OP-amp = AD795, $R_f = 10 \text{ M}\Omega$ and $C_f = 1\text{pF}$.